L Number	Hits	Search Text	DB	Time stamp
-	2	("6677613").PN.	USPAT;	2004/10/21
·		(00//020 , 0220	US-PGPUB; EPO; JPO;	11:08
	2	"20040036071"	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/10/21 11:08
_	1	"5463483".PN.	IBM_TDB USPAT	2004/10/21
-	1	"5594569".PN.	USPAT	2004/10/21 11:23
-	1	"5856689".PN.	USPAT	2004/10/21
-	1	"5904514".PN.	USPAT	2004/10/21 11:25
-	1	"5998841".PN.	USPAT	2004/10/21
_	1	"6162654".PN.	USPAT	2004/10/21
_	1	"6208392".PN.	USPAT	2004/10/21
-	1	"6271543".PN.	USPAT	2004/10/21 11:29
_	704	@ad<=19990303 and (257/72).ccls.	USPAT; US-PGPUB;	2004/10/21 12:01
-	385	@ad<=19990303 and (257/79).ccls,.	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/10/21
_	648	@ad<=19990303 and (257/40).ccls.	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/10/21 11:56
	91	@ad<=19990303 and (257/83).ccls.	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2004/10/21 11:56
	450	@ad<=19990303 and (257/88).ccls.	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/10/21 11:56
_	261	<pre>@ad<=19990303 and 'liquid crystal display' and 'transistor' and 'light shielding layer' and 'pixel electrode'</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/10/21 11:58
_	34	<pre>@ad<=19990303 and 'liquid crystal display' and 'transistor' and 'light shielding layer' and 'pixel electrode' and 'storage capacitance'</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/10/21 14:13
_	1812	@ad<=19990303 and (345/87).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 12:02

_	537	@ad<=19990303 and (345/92).ccls.	USPAT;	2004/10/21
			US-PGPUB; EPO; JPO;	12:05
			DERWENT;	
			IBM_TDB	
-	998	@ad<=19990303 and (345/102-104).ccls.	USPAT;	2004/10/21
,			US-PGPUB; EPO; JPO;	12:04
		`	DERWENT;	
			IBM_TDB	
-	784	@ad<=19990303 and (345/94).ccls.	USPAT;	2004/10/21
			US-PGPUB; EPO; JPO;	13:11
			DERWENT;	
			IBM_TDB	
_	1	"6157429".PN.	USPAT	2004/10/21
_	1	"6127998".PN.	USPAT	13:05 2004/10/21
	1	0127330 .I.K.	OSTAI	13:06
-	1	"5827755".PN.	USPAT	2004/10/21
	_	, , , , , , , , , , , , , , , , , , ,		13:06 ,
-	1	"5815223".PN.	USPAT	2004/10/21 13:07
_	1	"5691794".PN.	USPAT	2004/10/21
				13:09
-	1	"5591990".PN.	USPAT	2004/10/21
_	1	"5200926".PN.	USPAT	13:10 2004/10/21
	1	0200320		13:11
-	1282	@ad<=19990303 and (349/42).ccls.	USPAT;	2004/10/21
			US-PGPUB;	13:12
			EPO; JPO; DERWENT;	
			IBM TDB	·
-	1625	@ad<=19990303 and (349/139).ccls	USPAT;	2004/10/21
;			US-PGPUB;	13:14
			EPO; JPO; DERWENT;]
		·	IBM_TDB	
	1011	@ad<=19990303 and (349/138).ccls	USPAT;	2004/10/21
			US-PGPUB; EPO; JPO;	13:15
			DERWENT;	
			IBM_TDB	
-	1360	@ad<=19990303 and (349/158).ccls	USPAT;	2004/10/21
			US-PGPUB; EPO; JPO;	13:17
			DERWENT;	
			IBM_TDB	0003455455
-	130	@ad<=19990303 and (349/145).ccls	USPAT; US-PGPUB;	2004/10/21
			EPO; JPO;	13.27
			DERWENT;	
	100	0-4-10000000 1 (200 (20) - 3	IBM_TDB	2004/10/01
_	108	@ad<=19990303 and (368/30).ccls	USPAT; US-PGPUB;	2004/10/21
			EPO; JPO;	
			DERWENT;	
		And <-10000202 1-1	IBM_TDB	2004/10/21
_	3	<pre>@ad<=19990303 and 'electro-optical device' and 'silicon substrate' and</pre>	USPAT; US-PGPUB;	2004/10/21 13:53
		'active matrix pixel'	EPO; JPO;	
{			DERWENT;	
_	1 4		IBM_TDB	2004/10/21
	14	@ad<=19990303 and 'LCD' and 'silicon substrate' and 'resin' and 'shielding	USPAT; US-PGPUB;	2004/10/21 13:54
		layer' and 'pixel'	EPO; JPO;	
	1		DERWENT;	
	<u></u>	<u> </u>	IBM_TDB	

			T	
_	3	@ad<=19990303 and 'silicon substrate' and	USPAT;	2004/10/21
		'transistor' and 'light shielding layer'	US-PGPUB;	14:56
		and 'pixel electrode' and 'storage	EPO; JPO;	
		capacitance'	DERWENT; IBM TDB	
_	79	@ad<=19990303 and 'dielectric' same 'SiO'	USPAT;	2004/10/21
	"	same 'polyimide'	US-PGPUB;	14:58
		bame poryrmiae	EPO; JPO;	11.30
			DERWENT;	
			IBM TDB	.
-	45	@ad<=19990303 and 'dielectric' same 'SiO'	USPAT;	2004/10/21
		with 'polyimide'	US-PGPUB;	15:15
			EPO; JPO;	
·			DERWENT;	
			IBM_TDB	
-	74	@ad<=19990303 and 'dielectric' with 'SOG'	USPAT;	2004/10/21
		with 'polyimide'	US-PGPUB;	15:05
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	6	@ad<=19990303 and 'dielectric' with 'SOG'	USPAT;	2004/10/21
		with 'BCB'	US-PGPUB;	15:07
			EPO; JPO;	
			DERWENT;	
	1	<pre>@ad<=19990303 and 'dielectric' same 'SOG'</pre>	IBM_TDB USPAT;	2004/10/21
		same 'P' adj1 'SiO'	US-PGPUB;	2004/10/21
		Same P adji Sio	EPO; JPO;	15:08
			DERWENT;	
			IBM TDB	
_	5	@ad<=19990303 and 'dielectric' same 'P'	USPAT;	2004/10/21
		adj1 'SiO'	US-PGPUB;	15:09
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	1	@ad<=19990303 and 'dielectric' same 'SiO'	USPAT;	2004/10/21
		with 'BCB'	US-PGPUB;	15:16
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	14	<pre>@ad<=19990303 and 'dielectric' same 'SiO'</pre>	USPAT;	2004/10/22
		with 'polyamide'	US-PGPUB;	09:20
	;	•	EPO; JPO;	,
			DERWENT;	
		0.4<-10000303 144-1	IBM_TDB	2004/10/22
_	1	<pre>@ad<=19990303 and 'dielectric' same 'PSG'</pre>	USPAT;	2004/10/22
	<u> </u>	with 'BPSG' with 'BCB'	US-PGPUB;	09:21
			EPO; JPO; DERWENT;	1
	[IBM TDB	
1_	1	<pre>@ad<=19990303 and 'dielectric' same 'PSG'</pre>	USPAT;	2004/10/22
		with 'BCB'	US-PGPUB;	09:21
]	_ 	EPO; JPO;	
			DERWENT;	
	}		IBM TDB	
] -	61	@ad<=19990303 and 'dielectric' with 'PSG'	USPAT;	2004/10/22
		with 'polyimide'	US-PGPUB;	09:34
]			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
 -	2	("6157429").PN.	USPAT;	2004/10/22
]			US-PGPUB;	09:34
			EPO; JPO;	
			DERWENT;	
			IBM TDB	<u> </u>